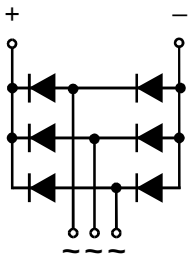
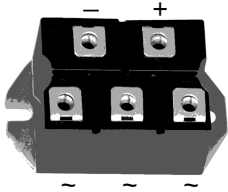


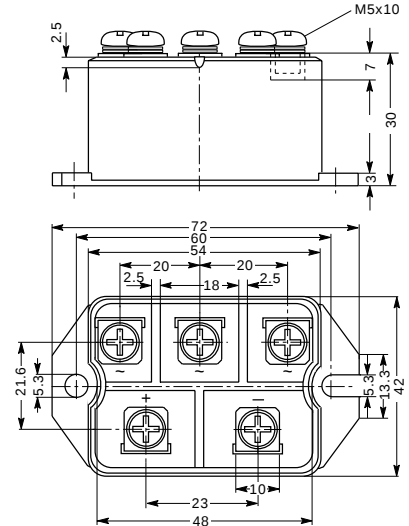
S3PDB80

Three Phase Rectifier Modules



Type	V_{RSM} V	V_{RRM} V
S3PDB80N08	900	800
S3PDB80N12	1300	1200
S3PDB80N14	1500	1400
S3PDB80N16	1700	1600
S3PDB80N18	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I_{dav}	$T_C=110^{\circ}C$, module	80	A
I_{dav}	$T_A=45^{\circ}C$ ($R_{thCA}=0.6K/W$), module	57	
I_{FSM}	$T_{VJ}=45^{\circ}C$ $V_R=0$ $t=10ms$ (50Hz), sine	750	A
	$t=8.3ms$ (60Hz), sine	820	
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10ms$ (50Hz), sine	670	
	$t=8.3ms$ (60Hz), sine	740	
I^2t	$T_{VJ}=45^{\circ}C$ $V_R=0$ $t=10ms$ (50Hz), sine	2800	A^2s
	$t=8.3ms$ (60Hz), sine	2800	
	$T_{VJ}=T_{VJM}$ $V_R=0$ $t=10ms$ (50Hz), sine	2250	
	$t=8.3ms$ (60Hz), sine	2250	
T_{VJ}		-40...+150	$^{\circ}C$
T_{VJM}		150	
T_{stg}		-40...+125	
V_{ISOL}	50/60Hz, RMS $I_{ISOL} \leq 1mA$ $t=1min$ $t=1s$	2500 3000	$V\sim$
M_d	Mounting torque (M5) Terminal connection torque (M5)	$5 \pm 15\%$ $5 \pm 15\%$	Nm
Weight	typ.	160	g

S3PDB80

Three Phase Rectifier Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_R	$V_R = V_{RRM}; T_{VJ} = 25^{\circ}\text{C}$ $V_R = V_{RRM}; T_{VJ} = T_{VJM}$	≤ 0.3 ≤ 5	mA
V_F	$I_F = 150\text{A}; T_{VJ} = 25^{\circ}\text{C}$	≤ 1.6	V
V_{TO}	For power-loss calculations only	0.8	V
r_T	$T_{VJ} = T_{VJM}$	5	$\text{m}\Omega$
R_{thJC}	per diode per module	1.1 0.183	K/W
R_{thJK}	per diode per module	1.52 0.253	K/W
d_s	Creeping distance on surface	10	mm
d_A	Creepage distance in air	9.4	mm
a	Max. allowable acceleration	50	m/s^2

FEATURES

- * Package with screw terminals
- * Isolation voltage 3000 V~
- * Planar passivated chips
- * Blocking voltage up to 1800 V
- * Low forward voltage drop

APPLICATIONS

- * Supplies for DC power equipment
- * Input rectifiers for PWM inverter
- * Battery DC power supplies
- * Field supply for DC motors

ADVANTAGES

- * Easy to mount with two screws
- * Space and weight savings
- * Improved temperature and power cycling